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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/761,881	01/20/2004	Chih-Wei Huang	67,200-1225	3162
7590 04/18/2007 TUNG & ASSOCIATES			EXAMINER	
Suite 120			KACKAR, RAM N	
838 W. Long Lake Road Bloomfield Hills, MI 48302			ART UNIT	PAPER NUMBER
	,		1763	
SHORTENED STATUTOR	RY PERIOD OF RESPONSE	MAIL DATE	DELIVERY MODE	
. 3 MONTHS		04/18/2007	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

	Application No.	Applicant(s)				
· ·	10/761,881	HUANG ET AL.				
Office Action Summary	Examiner	Art Unit				
·	Ram N. Kackar	1763				
The MAILING DATE of this communication ap	opears on the cover sheet wit	h the correspondence address				
Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING I - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statu Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNIC .136(a). In no event, however, may a re d will apply and will expire SIX (6) MONT te, cause the application to become ABA	ATION. bly be timely filed HS from the mailing date of this communication. INDONED (35 U.S.C. § 133).				
Status		•				
1) Responsive to communication(s) filed on 03.	August 2006.					
·— · · · · · · · · · · · · · · · · · ·	is action is non-final.					
<i>,</i> —						
closed in accordance with the practice under						
Disposition of Claims						
4) Claim(s) <u>1-12 and 17-20</u> is/are pending in the	e application.					
4a) Of the above claim(s) <u>17-20</u> is/are withdra	• •					
5) Claim(s) is/are allowed.		·				
6)⊠ Claim(s) <u>1-12</u> is/are rejected.	•					
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/	or election requirement.					
Application Papers						
9)☐ The specification is objected to by the Examir	ner.					
10)☐ The drawing(s) filed on is/are: a)☐ ac	cepted or b) objected to b	y the Examiner.				
Applicant may not request that any objection to the	e drawing(s) be held in abeyand	e. See 37 CFR 1.85(a).				
Replacement drawing sheet(s) including the corre	ction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).				
11) The oath or declaration is objected to by the E	Examiner. Note the attached	Office Action or form PTO-152.				
Priority under 35 U.S.C. § 119		•				
12) Acknowledgment is made of a claim for foreig a) All b) Some * c) None of:	n priority under 35 U.S.C. §	119(a)-(d) or (f).				
1. Certified copies of the priority documer	nts have been received.					
2. Certified copies of the priority documer	nts have been received in Ap	plication No				
3. Copies of the certified copies of the pri	ority documents have been r	eceived in this National Stage				
application from the International Burea	• • • • • • • • • • • • • • • • • • • •					
* See the attached detailed Office action for a lis	t of the certified copies not r	eceived.				
·						
Attachment(s)		·				
) Notice of References Cited (PTO-892)	4) 🔲 Interview Su	mmary (PTO-413)				
Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)	Mail Date				
Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	5) Notice of Inf 6) Other:	ormal Patent Application				

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DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 12/29/2006 has been entered.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1-2, 6, 9-10 and 12 are rejected under 35 U.S.C. 102(b) as being anticipated by or, in the alternative, under 35 U.S.C. 103(a) as obvious over Ke et al (US 6284093).

Ke et al disclose an insert ring (Fig 6-50) with an annular step (58) encircling a wafer support in a plasma-processing chamber (Col 8 lines 28-38). The insert ring is surrounded and supported by a shadow ring (30) where in the shadow ring is extending vertically higher than insert ring. The insert ring comprises silicon (Col 7 lines 65-67).

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4. Claims 1, 6, 9 and 12 are rejected under 35 U.S.C. 102(b) as being anticipated by or, in the alternative, under 35 U.S.C. 103(a) as obvious over Ishii et al (US 5529657).

Ishii et al disclose an insert ring (Fig 5-6b) with an annular step encircling a wafer support in a plasma-processing chamber. The insert ring is surrounded and supported by a shadow ring (6a) where in the shadow ring is extending vertically higher than insert ring.

5. Claims 1-2, 6, 9-10 and 12 are rejected under 35 U.S.C. 102(b) as being anticipated by or, in the alternative, under 35 U.S.C. 103(a) as obvious over Daugherty et al (US 6344105).

Daugherty et al disclose an insert ring (Fig 5-508) with an annular step encircling a wafer support in a plasma-processing chamber. The insert ring is surrounded and supported by a shadow ring (512) where in the shadow ring is extending vertically higher than insert ring. The insert ring comprises semiconductor material which could be doped like silicon carbide (Col 7 line 66 Col 7 line 21).

Claim Rejections - 35 USC § 103

6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

7. Claims 1-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kanno et al (US 20030029572) in view of Ke et al (US 6284093).

Kanno et al disclose an as insert ring (focus ring Fig 8-32) of silicon (Paragraph 60) with an annular step encircling a wafer support in a plasma processing chamber. The insert ring is surrounded by a shadow ring (unnumberd part) and is supported by it.

Kanno et al do not disclose the outer portion of shadow ring extending vertically higher than insert ring.

Ke et al disclose an insert ring (Fig 6-50) with an annular step (58) encircling a wafer support in a plasma-processing chamber (Col 8 lines 28-38). The insert ring is surrounded and supported by a shadow ring (30) where in the shadow ring is extending vertically higher than insert ring. The insert ring comprises silicon (Col 7 lines 65-67). Ke et el further teach that the height of the shadow ring affects the processing in several ways like depletion effect near the perimeter, confinement time of reactive species near the perimeter and focusing effect.

Therefore it would be obvious to one of ordinary skill in the art at the time of invention to adjust the height of the shadow ring to control process uniformity.

8. Claims 3-5, 7-8 and 11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ke et al (US 6284093) in view of Park et al (US 6464794).

Ke et al do not explicitly disclose the height of the insert ring as in Fig 6.

Park et al disclose an insert ring (edge ring Fig 2-24) of silicon (Col 5 lines 42-45) with an annular step encircling a wafer support in a plasma-processing chamber.

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Park et al do not explicitly disclose the height of the edge ring as in Fig 2-24 but disclose that in general the height is 3-6-4.5 mm (Col 8 lines 20-30). Further the height of the taller part could be increased by 2-4-3.0 mm (Col 10 lines 62-67). Park further teaches that the height is determined by process requirement as the focus ring height is known to affect the plasma orientation and the lift of the ring expected.

Therefore having a height of 3.5 mm of one part and of 1.5 mm of the other part would have been an obvious compromise for one of ordinary skill in the art at the time of invention.

Response to Arguments

Applicant's arguments filed 12/29/2006 have been fully considered but they are not persuasive.

Applicant argues against the references sited. In response several rejections are removed. However rejections as above stand as new limitations are submitted.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ram N. Kackar whose telephone number is 571 272 1436. The examiner can normally be reached on M-F 8:00 A.M to 5:P.M.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on 571 272 1435. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Ram Kackar

Primary Examiner AU 1763